

IN THE CLAIMS:

1-18. (Canceled)

19. (Previously Presented) An electroluminescence display apparatus comprising:

- a first electrode formed above a substrate;
- an emissive element layer formed on said first electrode;
- a second electrode formed on said emissive element; and
- a thickness of said first electrode is less than $1/2$ a thickness of said emissive element layer, said thickness of said emissive element layer is approximately 200 nm.

20. (Previously Presented) An electroluminescence display apparatus comprising:

- a first electrode formed above a substrate;
- an emissive element layer formed on said first electrode;
- a second electrode formed on said emissive element; and
- a thickness of said first electrode is less than $1/3$ a thickness of said emissive element layer, said thickness of said emissive element layer is approximately 200 nm.

21. (Previously Presented) An electroluminescence display apparatus according to claim 19 is an active-matrix type comprising said first electrode formed independently at each pixel, and thin-film transistor for driving said emissive element.

22. (Previously Presented) An electroluminescence display apparatus according to claim 21 further comprising the planarization insulating film formed so as to cover said thin-film transistor, with said first electrode formed on said planarization insulating film.

23. (Previously Presented) An electroluminescence display apparatus according to claim 21 wherein said emissive element layer comprises a layered structure of a hole transport layer, an emissive layer, and an electron transport layer.

24. (Previously Presented) An electroluminescence display apparatus according to claim 19 is a passive-matrix type wherein said first electrode extends in a first direction and said second electrode extends in a second direction so as to intersect said first electrode.

25. (Previously Presented) An electroluminescence display apparatus according to claim 24 wherein said emissive element layer comprises a layered structure of a hole transport layer, an emissive layer, and an electron transport layer.

26. (Previously Presented) An electroluminescence display apparatus comprising:

- a first electrode formed above a substrate;
- an emissive element layer formed on said first electrode, the emissive element layer comprises an organic layer that includes at least organic emissive molecules;
- a second electrode formed on said emissive element; and
- a thickness of said first electrode is less than 1/2 the thickness of said emissive element layer.

27. (Previously Presented) An electroluminescence display apparatus comprising:

- a first electrode formed above a substrate;
- an emissive element layer formed on said first electrode, the emissive element layer comprises an organic layer that includes at least organic emissive molecules;
- a second electrode formed on said emissive element; and
- a thickness of said first electrode is less than 1/3 a thickness of said emissive element layer.